

# RJH60M2DPE

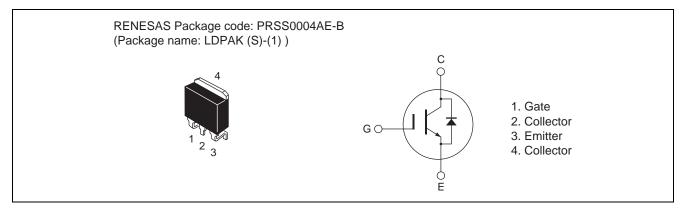
600V - 12A - IGBT Application: Inverter R07DS0531EJ0300 Rev.3.00 May 25, 2012

### Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage  $V_{CE(sat)} = 1.9$  V typ. (at I<sub>C</sub> = 12 A, V<sub>GE</sub> = 15 V, Ta = 25°C)
- Built in fast recovery diode (85 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 45$  ns typ. (at  $V_{CC} = 300$  V,  $V_{GE} = 15$  V,  $I_C = 12$  A, Rg = 5  $\Omega$ ,  $Ta = 25^{\circ}C$ , inductive load)

#### Outline



## **Absolute Maximum Ratings**

			<u> </u>	$(Ta = 25^{\circ}C)$
ltem		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V <sub>CES</sub> / V <sub>R</sub>	600	V
Gate to emitter voltage		V <sub>GES</sub>	±30	V
Collector current	Tc = 25°C	Ι <sub>C</sub>	25	А
	Tc = 100°C	Ι <sub>C</sub>	12	А
Collector peak current		ic(peak) Note1	36	А
Collector to emitter diode forward current		i <sub>DF</sub>	12	А
Collector to emitter diode forward peak current		i <sub>DF</sub> (peak) <sup>Note1</sup>	45	А
Collector dissipation		P <sub>C</sub> <sup>Note2</sup>	63	W
Junction to case thermal resistance (IGBT)		θj-c <sup>Note2</sup>	1.98	°C/W
Junction to case thermal resistance (Diode)		θj-cd <sup>Note2</sup>	2.8	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \ \mu s$ , duty cycle  $\le 1\%$ 

2. Value at Tc = 25°C



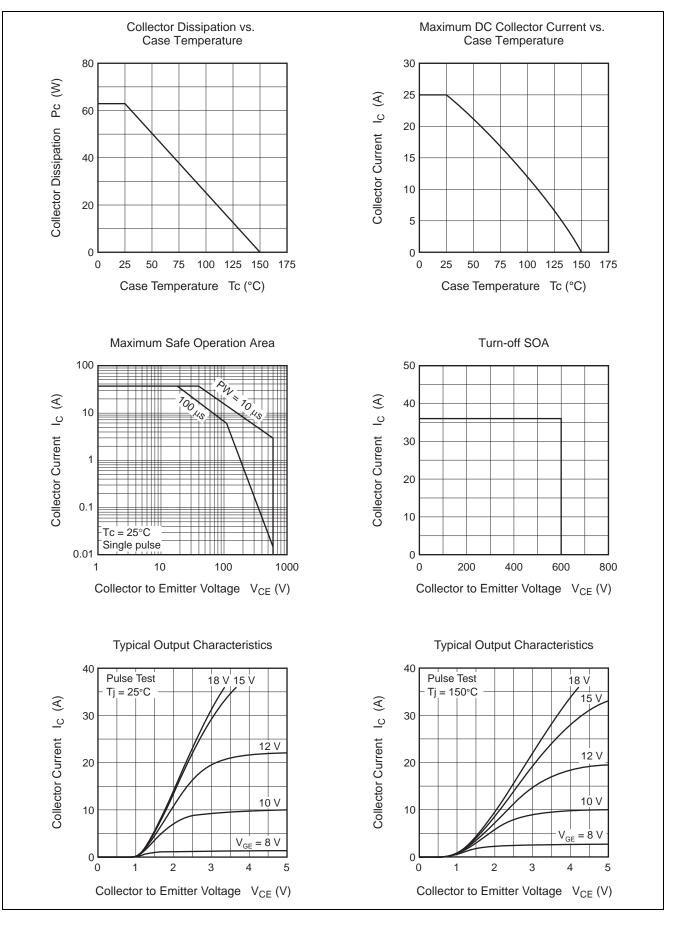
## **Electrical Characteristics**

Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V <sub>(BR)CES</sub>	600	—	—	V	$Iy = 10 \ \mu A, \ V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I <sub>CES</sub> / I <sub>R</sub>	_	—	5	μA	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I <sub>GES</sub>	_	—	±1	μA	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V <sub>GE(off)</sub>	5	—	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	1.9	2.5	V	$I_{C} = 12 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V <sub>CE(sat)</sub>	_	2.8	_	V	$I_{C} = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	430	_	pF	V <sub>CE</sub> = 25 V	
Output capacitance	Coes	_	40	_	pF	$V_{GE} = 0$	
Reverse transfer capacitance	Cres		15	_	pF	f = 1 MHz	
Total gate charge	Qg		33	_	nC	V <sub>GE</sub> = 15 V	
Gate to emitter charge	Qge		5	_	nC	V <sub>CE</sub> = 300 V	
Gate to collector charge	Qgc		19	_	nC	I <sub>C</sub> = 12 A	
Turn-on delay time	t <sub>d(on)</sub>		32	_	ns	V <sub>CC</sub> = 300 V	
Rise time	tr		18	_	ns	V <sub>GE</sub> = 15 V	
Turn-off delay time	t <sub>d(off)</sub>	_	70	—	ns	$I_{C} = 12 A$ Rg = 5 $\Omega$ Inductive load	
Fall time	t <sub>f</sub>	_	45	—	ns		
Turn-on energy	Eon	_	0.18	—	mJ		
Turn-off energy	E <sub>off</sub>	_	0.18	—	mJ		
Total switching energy	E <sub>total</sub>	_	0.36	—	mJ	1	
Short circuit withstand time	t <sub>sc</sub>	6	8	—	μS	$\label{eq:CC} \begin{array}{l} \mbox{Tc} = 100 \ ^{\circ}\mbox{C} \\ \mbox{V}_{\mbox{CC}} \ \leq 360 \ \mbox{V}, \ \mbox{V}_{\mbox{GE}} = 15 \ \mbox{V} \end{array}$	
FRD Forward voltage	VF		1.2	1.6	V	$I_F = 12 \text{ A}^{\text{Note3}}$	
FRD reverse recovery time	t <sub>rr</sub>	_	85	_	ns	I <sub>F</sub> = 12 A	
FRD reverse recovery charge	Q <sub>rr</sub>	_	0.14	_	μC	di <sub>F</sub> /dt = 100 A/µs	
FRD peak reverse recovery current	-sii Irr		4.2		A	-	

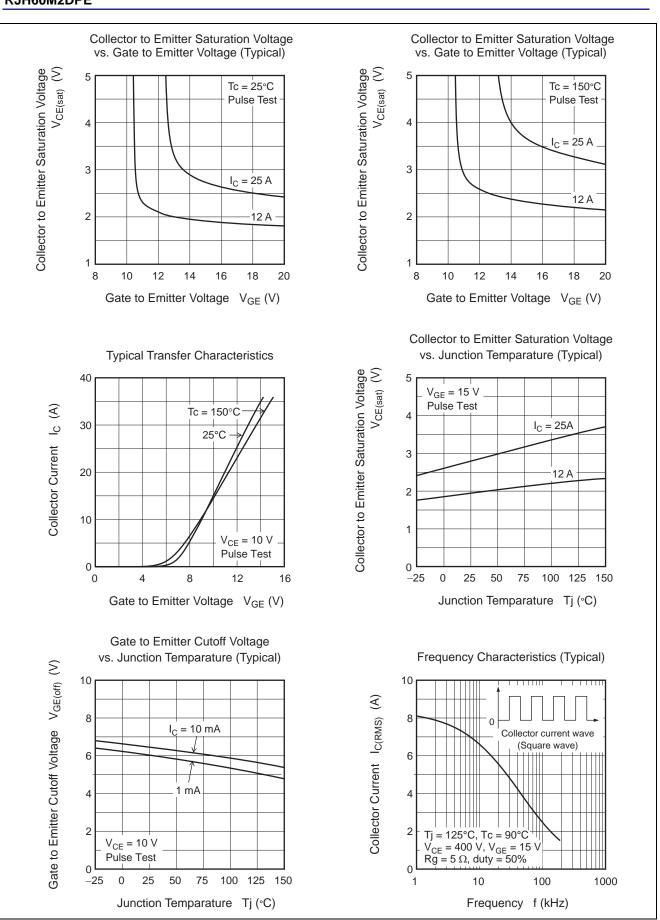
Notes: 3. Pulse test.



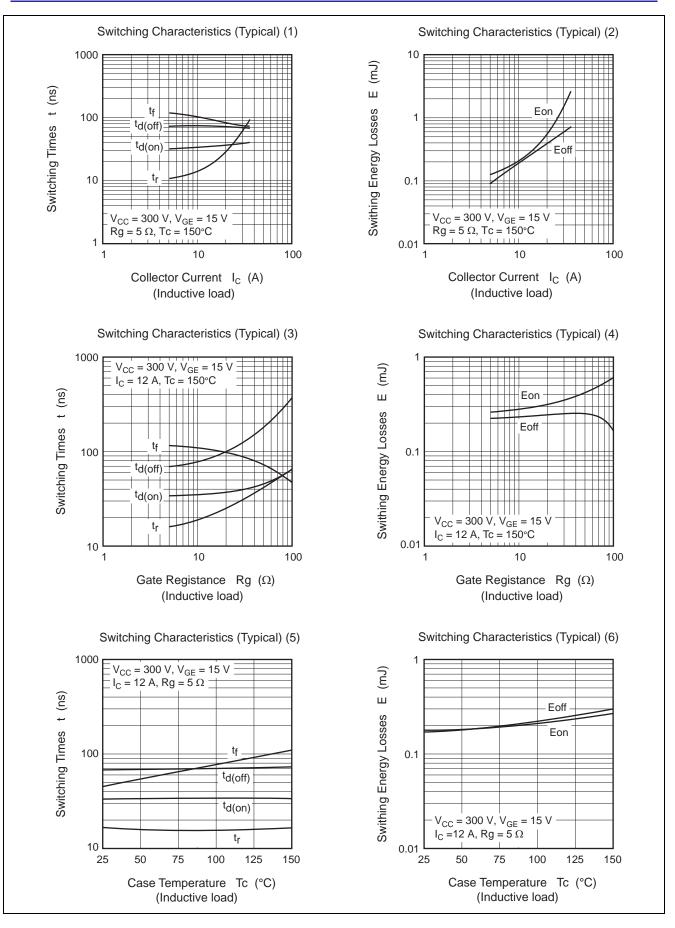
#### **Main Characteristics**

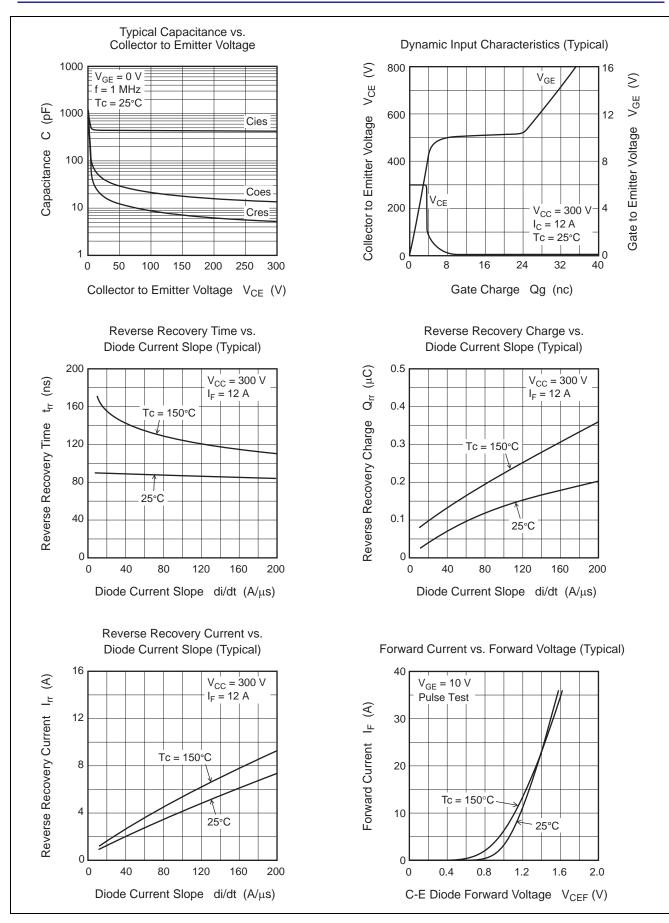




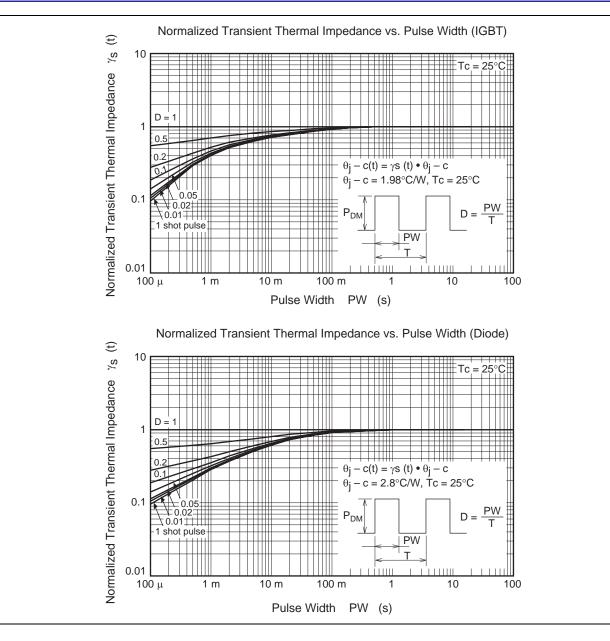




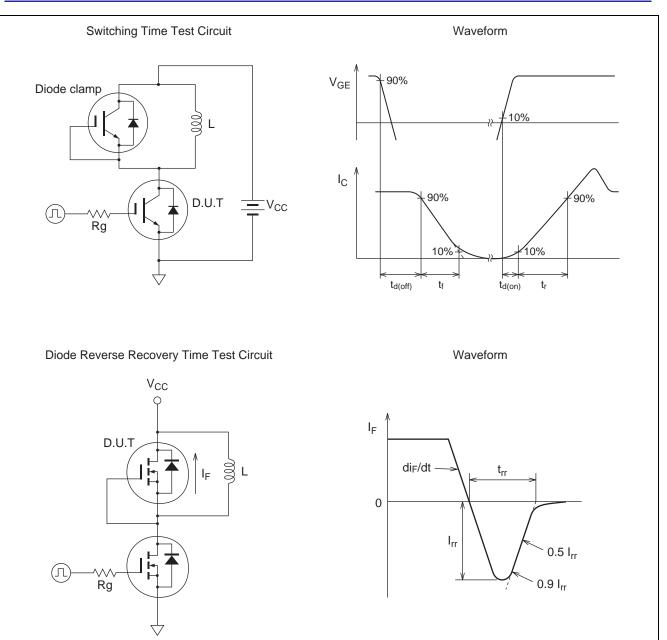






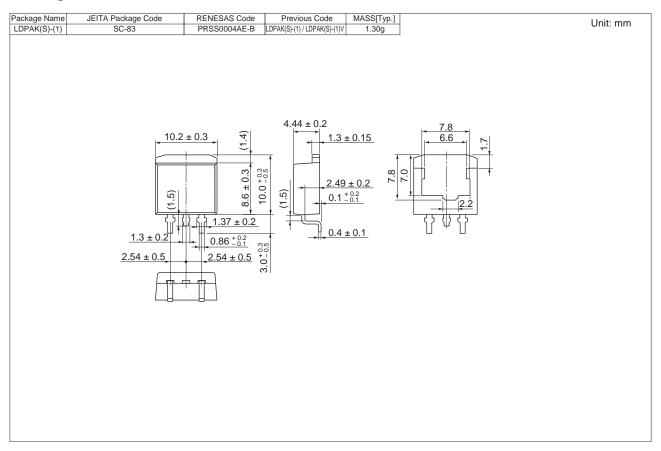








#### **Package Dimension**



### **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJH60M2DPE-00#J3	1000 pcs	Taping



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